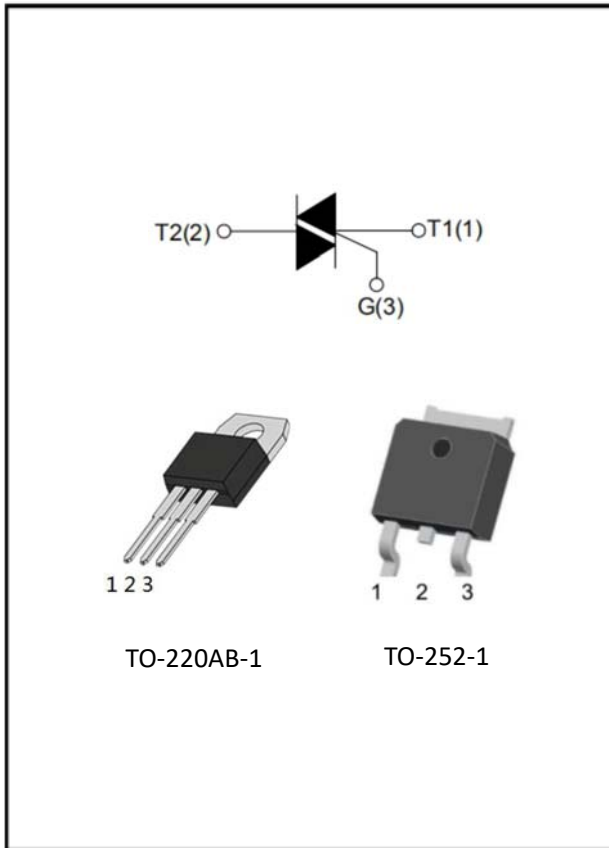


4A 4Q Triac



Features

- On-state rms current, $I_{T(RMS)}$ 4 A
- Repetitive peak off-state voltage, V_{DRM}/V_{RRM} 600 V
- Triggering gate current, $I_{GT(Q1)}$ 10 mA

Applications

- General purpose switching and phase control
- General purpose switching

Mechanical Data

- Case Material: "Green" Molding Compound
- Package: TO-220AB-1; TO-252-1

| DEVICE | PACAKGE |
|---------------|------------|
| ACYMB0425-06A | TO-220AB-1 |
| ACYMB0425-06D | TO-252-1 |

Main Characteristics

| SYMBOL | LIMITS | UNIT |
|-------------------|--------|------|
| $I_{T(RMS)}$ | 4 | A |
| V_{DRM}/V_{RRM} | 600 | V |
| I_{GT} | 10 | mA |

■Maximum Ratings

| PARAMETER | SYMBOL | LIMITS | UNIT |
|---|--------------|---------|----------------------|
| Storage junction temperature range | T_{stg} | -40~150 | °C |
| Operating junction temperature range | T_j | -40~125 | °C |
| Repetitive surge peak Off-state voltage ($T_j=25^\circ\text{C}$) | V_{DRM} | 600 | V |
| Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$) | V_{RRM} | 600 | V |
| RMS on-state current | $I_{T(RMS)}$ | 4 | A |
| Non-repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$) | I_{TSM} | 35 | A |
| I^2t value for fusing ($t_p=10\text{ms}$) | I^2t | 6.1 | A^2s |
| Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$) | di/dt | 50 | A/ μs |
| | | 10 | |
| Peak gate current | I_{GM} | 2 | A |
| Average gate power dissipation | $P_{G(AV)}$ | 0.5 | W |
| Peak gate power | P_{GM} | 5 | W |



ACYMB0425 Series

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | TEST CONDITIONS | QUADRANT | MIN | TYP | MAX |
|-----------------------------------|-----------------|------|--|-------------------|-----|-----|-----|
| Gate trigger current | I _{GT} | mA | V _D =12V, R _L =33Ω | I - II - III | | | 10 |
| | | | | IV | | | 25 |
| Gate trigger voltage | V _{GT} | V | V _D =12V, R _L =33Ω | I - II - III - IV | | | 1.3 |
| Non-triggering gate voltage | V _{GD} | V | V _D =V _{DRM} | I - II - III - IV | 0.2 | | |
| Holding current | I _H | mA | I _T =100mA | I - II - III - IV | | | |
| Latching current | I _L | mA | I _G =1.2 I _{GT} | I - III - IV | | | 20 |
| | | | | II | | | 35 |
| Rate of rise of off-state voltage | dV/dt | V/μs | V _D =0.66×V _{DRM} T _j =125°C Gate open | I - II - III - IV | 50 | | |

■Static Characteristics (T_a=25°C Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | TEST CONDITIONS | MAX |
|--|--------------------------------------|------|---|-----|
| Peak on-state voltage | V _{TM} | V | I _{TM} =5.5A t _p =380μs | 1.6 |
| Peak off-state current Peak reverse current | I _{DRM} I _{RRM} | μA | V _{DRM} = V _{RRM} , T _j =25°C | 5 |
| | | mA | V _{DRM} = V _{RRM} , T _j =125°C | 0.5 |

■Thermal Resistance (T_a=25°C Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | Package | Value | |
|---------------------------------|------------------|-------------------|---------|------------|-----|
| Thermal Resistance (Typical) | Junction to case | R _{θJ-C} | °C/W | TO-220AB-1 | 2.6 |
| | | | °C/W | TO-252-1 | 2.8 |



■ Characteristics (Typical)

FIG.1: Maximum power dissipation versus RMS on-state current

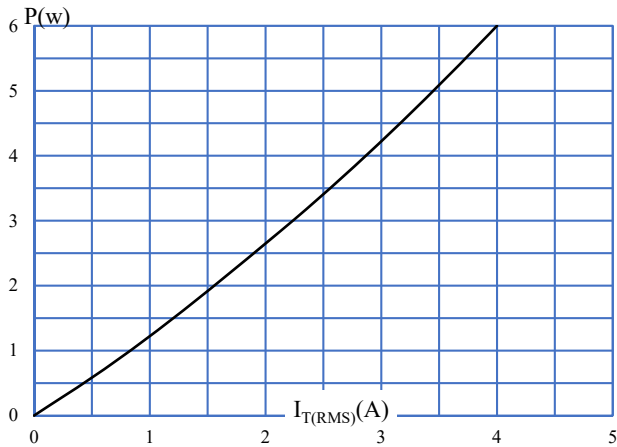


FIG.2: RMS on-state current versus case temperature

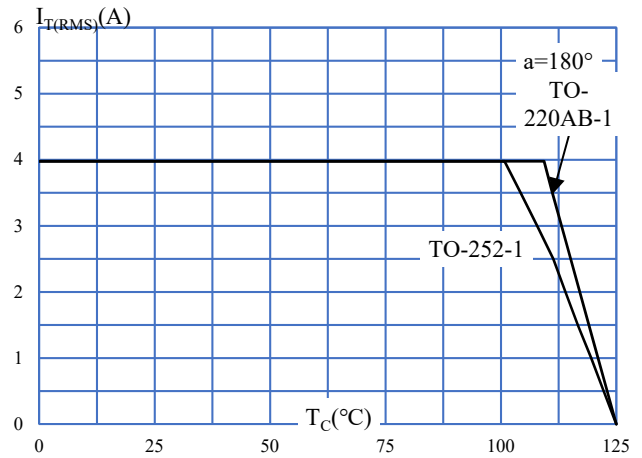


FIG.3: Surge peak on-state current versus number of cycles

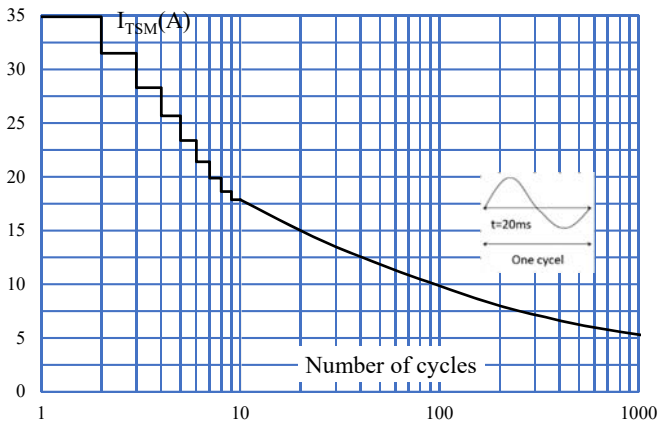


FIG.4: On-state characteristics(maximum values)

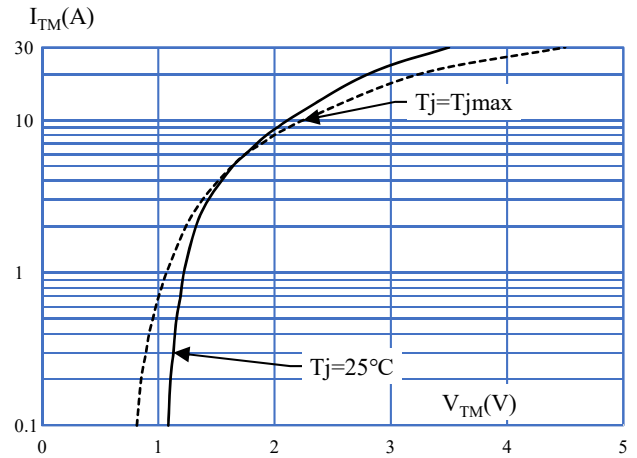


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t ($I - II - III: di/dt < 50\text{A}/\mu\text{s}; IV: di/dt < 10\text{A}/\mu\text{s}$)

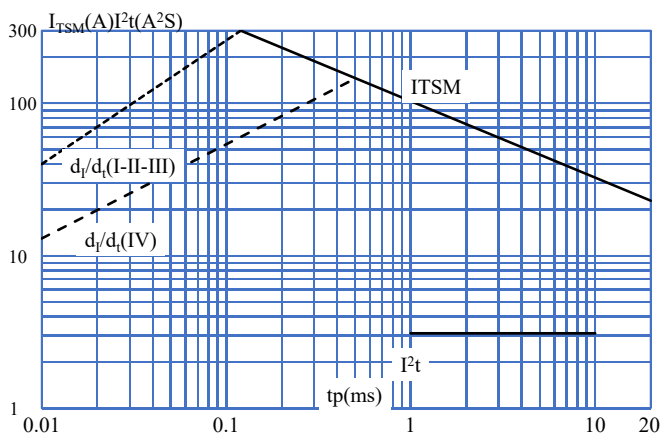
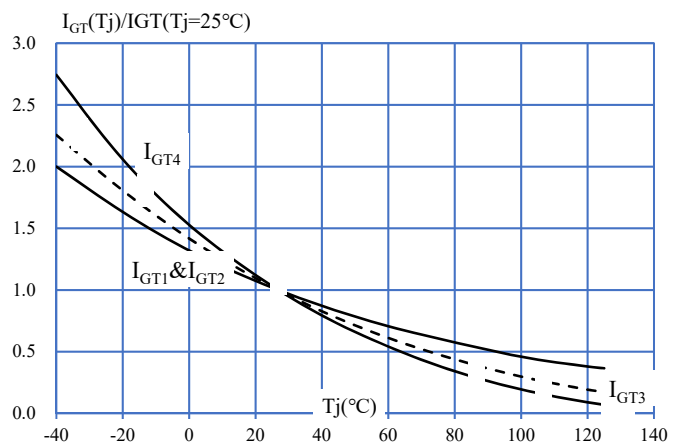


FIG.6: Relative variations of gate trigger current versus junction temperature





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FIG.7: Relative variations of holding current versus junction temperature

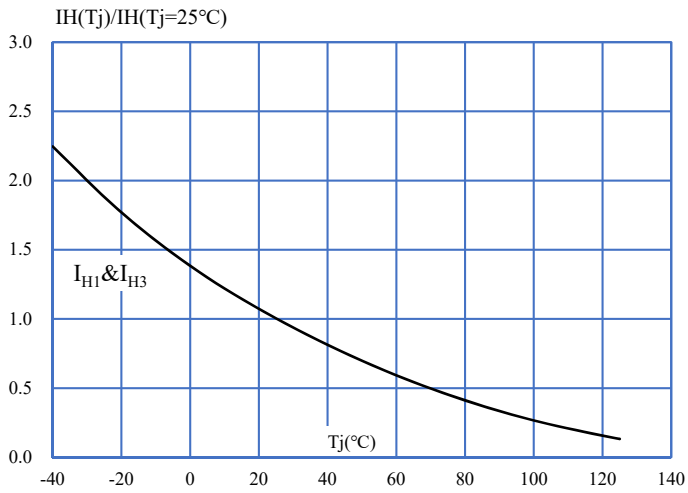
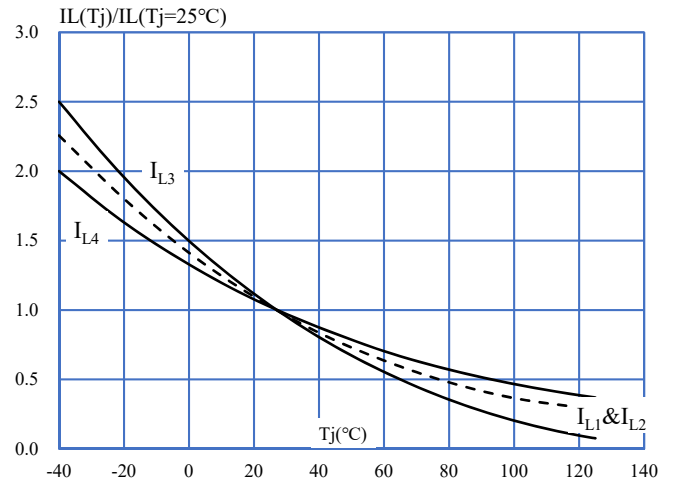
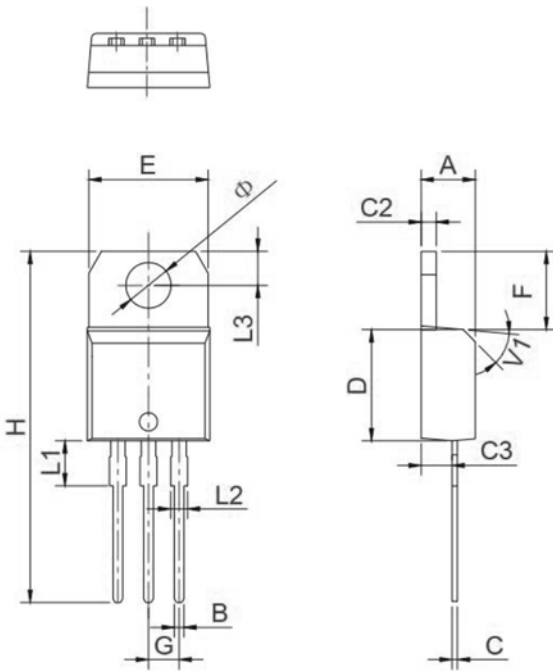


FIG.8: Relative variations of latching current versus junction temperature



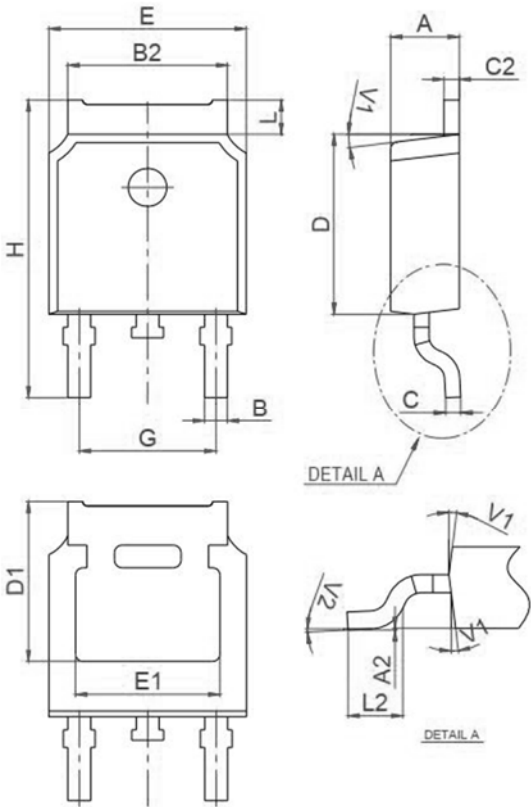
■ Outline Dimensions



| Symbol | Min.(mm) | Typ.(mm) | Max.(mm) |
|--------|----------|----------|----------|
| A | 2.2 | | 2.4 |
| A2 | 0 | | 0.1 |
| B | 0.66 | | 0.86 |
| B2 | 5.1 | | 5.46 |
| C | 0.46 | | 0.58 |
| C2 | 0.44 | | 0.58 |
| D | 5.9 | | 6.3 |
| D1 | | 5.30 | |
| E | 6.4 | | 6.8 |
| E1 | 4.63 | | |
| G | 4.372 | | 4.772 |
| H | 9.8 | | 10.4 |
| L | 1.09 | | 1.21 |
| L2 | 1.35 | | 1.65 |
| V1 | | 7° | |
| V2 | 0° | | 6° |

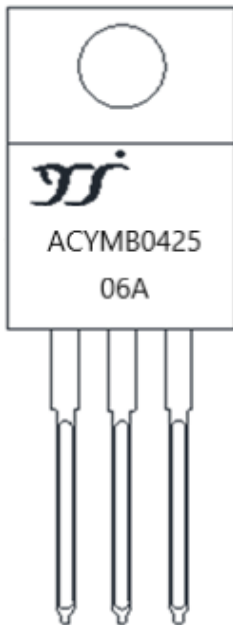


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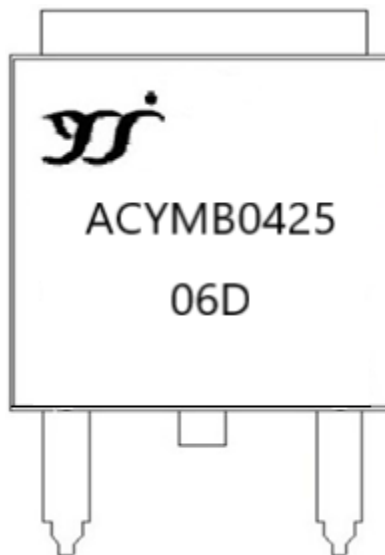


| Symbol | Min.(mm) | Typ.(mm) | Max.(mm) |
|--------|----------|----------|----------|
| A | 4.4 | 4.47 | 4.6 |
| B | 0.61 | | 0.88 |
| C | 0.46 | 0.50 | 0.7 |
| C2 | 1.21 | 1.27 | 1.32 |
| C3 | 2.4 | | 2.72 |
| D | 8.6 | | 9.7 |
| E | 9.8 | | 10.4 |
| F | 6.56 | | 6.95 |
| G | | 2.54 | |
| H | 28 | | 29.8 |
| L1 | | 3.75 | |
| L2 | 1.14 | | 1.7 |
| L3 | 2.65 | | 2.95 |
| V1 | | 45° | |
| Φ | 3.7 | 3.75 | 3.8 |

■ Marking information



(TO-220AB-1 Package)



(TO-252-1 Package)



ACYMB0425 Series

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